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Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length:	
1.453 inches	
Overall Diameter:	
0.667 inches	
Mounting Facility Quantity:	
1	
Joint Electronic Device Engineering Council/jedec/case Outline Designation:	
D0-5	
Electrode Internally-electrically Connected To Case:	
Cathode	
Mounting Method:	
Threaded stud	
Overall Width Across Flats:	
Between 0.669 inches and 0.688 inches	
Thread Size:	
0.250 inches	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
400.0 reverse voltage, instantaneous and 400.0 working peak reverse voltage	
Current Rating Per Characteristic:	
300.00 amperes forward current, average preset	
Maximum Operating Tempurature Per Measurement Point:	
100.0 degrees celsius case	
Test Data Document:	
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type	e data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type	
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).	
Thread Series Designator:	
Unf	
Terminal Type And Quantity:	
1 threaded stud and 1 tab, solder lug	
Specification Data:	
81349-mil-s-19500/308 government specification	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	